

Unbuffered Inverter

MC74VHC1GU04

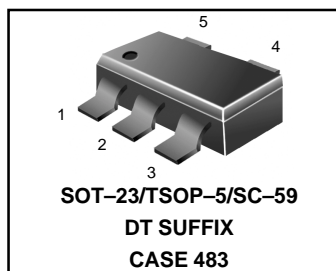
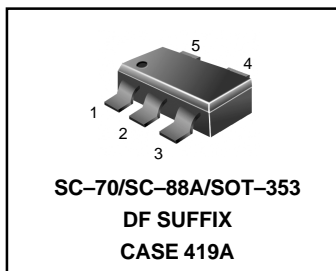
The MC74VHC1GU04 is an advanced high speed CMOS Unbuffered inverter fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

This device consists of a single unbuffered inverter. In combination with others, or in the MC74VHCU04 Hex Unbuffered Inverter, these devices are well suited for use as oscillators, pulse shapers, and in many other applications requiring a high-input impedance amplifier. For digital applications, the MC74VHC1G04 or the MC74VHC04 are recommended.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output.

The MC74VHC1GU04 input structure provides protection when voltages up to 7 V are applied, regardless of the supply voltage. This allows the MC74VHC1GU04 to be used to interface 5 V circuits to 3 V circuits.

- High Speed: $t_{PD} = 2.5 \text{ ns}$ (Typ) at $V_{CC} = 5 \text{ V}$
- Low Power Dissipation: $I_{CC} = 2 \text{ mA}$ (Max) at $T_A = 25^\circ\text{C}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Pin and Function Compatible with Other Standard Logic Families
- Chip Complexity: FETs = 105; Equivalent Gates = 26



MARKING DIAGRAMS

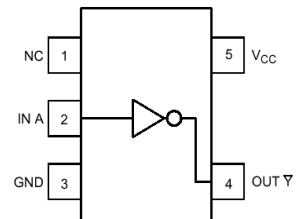
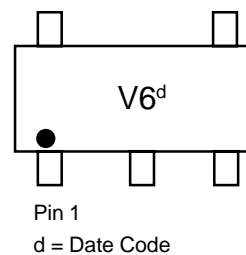
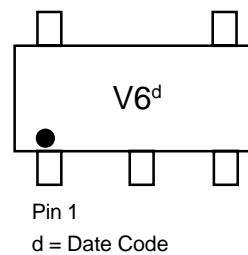


Figure 1. Pinout (Top View)



Figure 2. Logic Symbol

| PIN ASSIGNMENT | |
|----------------|---------------|
| 1 | NC |
| 2 | IN A |
| 3 | GND |
| 4 | OUT \bar{Y} |
| 5 | V_{CC} |

FUNCTION TABLE

| Inputs | Output |
|--------|-----------|
| A | \bar{Y} |
| L | H |
| H | L |

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MC74VHC1GU04

MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-----------------------|--|--|--|
| V _{CC} | DC Supply Voltage | - 0.5 to + 7.0 | V |
| V _{IN} | DC Input Voltage | - 0.5 to +7.0 | V |
| V _{OUT} | DC Output Voltage | V _{CC} =0 High or Low State | - 0.5 to +7.0 -0.5 to V _{CC} + 0.5 |
| I _{IK} | Input Diode Current | -20 | mA |
| I _{OK} | Output Diode Current | V _{OUT} < GND; V _{OUT} > V _{CC} | +20 mA |
| I _{OUT} | DC Output Current, per Pin | + 25 | mA |
| I _{CC} | DC Supply Current, V _{CC} and GND | +50 | mA |
| P _D | Power dissipation in still air | SC-88A, TSOP-5 | 200 mW |
| θ _{JA} | Thermal resistance | SC-88A, TSOP-5 | 333 °C/W |
| T _L | Lead Temperature, 1 mm from Case for 10 s | 260 | °C |
| T _J | Junction Temperature Under Bias | + 150 | °C |
| T _{stg} | Storage temperature | -65 to +150 | °C |
| V _{ESD} | ESD Withstand Voltage | Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4) | >2000 > 200 N/A V |
| I _{LATCH-UP} | Latch-Up Performance | Above V _{CC} and Below GND at 125°C (Note 5) | ± 500 mA |

1. Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.
2. Tested to EIA/JESD22-A114-A
3. Tested to EIA/JESD22-A115-A
4. Tested to JESD22-C101-A
5. Tested to EIA/JESD78

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
|---------------------------------|-----------------------------|--|-----------------|------------------------------|
| V _{CC} | DC Supply Voltage | 2.0 | 5.5 | V |
| V _{IN} | DC Input Voltage | 0.0 | 5.5 | V |
| V _{OUT} | DC Output Voltage | 0.0 | V _{CC} | V |
| T _A | Operating Temperature Range | - 55 | + 125 | °C |
| t _r , t _f | Input Rise and Fall Time | V _{CC} = 3.3 ± 0.3 V V _{CC} = 5.0 ± 0.5 V | 0 0 | No Limit No Limit ns/V |

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

| Junction Temperature °C | Time, Hours | Time, Years |
|-------------------------|-------------|-------------|
| 80 | 1,032,200 | 117.8 |
| 90 | 419,300 | 47.9 |
| 100 | 178,700 | 20.4 |
| 110 | 79,600 | 9.4 |
| 120 | 37,000 | 4.2 |
| 130 | 17,800 | 2.0 |
| 140 | 8,900 | 1.0 |

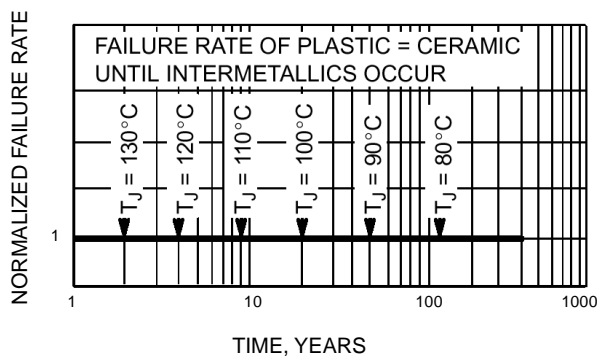


Figure 3. Failure Rate vs. Time Junction Temperature

MC74VHC1GU04
DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Conditions | V _{CC} (V) | T _A = 25°C | | | T _A ≤ 85°C | | -55°C ≤ T _A ≤ 125°C | | Unit |
|-----------------|---|--|------------------------|-----------------------|-----|------|-----------------------|------|--------------------------------|------|------|
| | | | | Min | Typ | Max | Min | Max | Min | Max | |
| V _{IH} | Minimum High-Level Input Voltage | | 2.0 | 1.7 | | | 1.7 | | 1.7 | | V |
| | | | 3.0 | 2.4 | | 2.4 | | 2.4 | | | |
| | | | 4.5 | 3.6 | | 3.6 | | 3.6 | | | |
| | | | 5.5 | 4.4 | | 4.4 | | 4.4 | | | |
| V _{IL} | Maximum Low-Level Input Voltage | | 2.0 | | | 0.3 | | 0.3 | | 0.3 | V |
| | | | 3.0 | | | 0.6 | | 0.6 | | 0.6 | |
| | | | 4.5 | | | 0.9 | | 0.9 | | 0.9 | |
| | | | 5.5 | | | 1.1 | | 1.1 | | 1.1 | |
| V _{OH} | Minimum High-Level Output Voltage V _{IN} = V _{IH} or V _{IL} | V _{IN} = V _{IH} or V _{IL} I _{OH} = -50 μA | 2.0 | 1.9 | 2.0 | | 1.9 | | 1.9 | | V |
| | | | 3.0 | 2.9 | 3.0 | | 2.9 | | 2.9 | | |
| | | | 4.5 | 4.4 | 4.5 | | 4.4 | | 4.4 | | |
| | | V _{IN} = V _{IH} or V _{IL} I _{OH} = -4 mA I _{OH} = -8 mA | 3.0 | 2.58 | | | 2.48 | | 2.34 | | |
| | | | 4.5 | 3.94 | | | 3.80 | | 3.66 | | |
| | | | | | | | | | | | |
| V _{OL} | Maximum Low-Level Output Voltage V _{IN} = V _{IH} or V _{IL} | V _{IN} = V _{IH} or V _{IL} I _{OL} = 50 μA | 2.0 | | 0.0 | 0.1 | | 0.1 | | 0.1 | V |
| | | | 3.0 | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | | 4.5 | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | V _{IN} = V _{IH} or V _{IL} I _{OL} = 4 mA I _{OL} = 8 mA | 3.0 | | | 0.36 | | 0.44 | | 0.52 | |
| | | | 4.5 | | | 0.36 | | 0.44 | | 0.52 | |
| | | | | | | | | | | | |
| I _{IN} | Maximum Input Leakage Current | V _{IN} = 5.5 V or GND | 0 to 5.5 | | | ±0.1 | | ±1.0 | | ±1.0 | μA |
| I _{CC} | Maximum Quiescent Supply Current | V _{IN} = V _{CC} or GND | 5.5 | | | 2.0 | | 20 | | 40 | μA |

AC ELECTRICAL CHARACTERISTICS C_{load} = 50 pF, Input t_r = t_f = 3.0 ns

| Symbol | Parameter | Test Conditions | T _A = 25°C | | | T _A ≤ 85°C | | -55°C ≤ T _A ≤ 125°C | | Unit |
|--|--|--|---|-----|------|-----------------------|------|--------------------------------|------|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Input A or B to \bar{Y} | V _{CC} = 3.3 ± 0.3 V C _L = 15 pF C _L = 50 pF | | 3.5 | 8.9 | | 10.5 | | 12.0 | ns |
| | | | | 4.8 | 11.4 | | 13.0 | | 15.5 | |
| C _{IN} | Maximum Input Capacitance | V _{CC} = 5.0 ± 0.5 V C _L = 15 pF C _L = 50 pF | | 2.5 | 5.5 | | 6.5 | | 8.0 | pF |
| | | | | 3.8 | 7.0 | | 8.0 | | 9.5 | |
| | | | Typical @ 25°C, V_{CC} = 5.0 V | | | | | | | |
| C _{PD} | Power Dissipation Capacitance (Note 6) | | 22 | | | | | | | pF |

6. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

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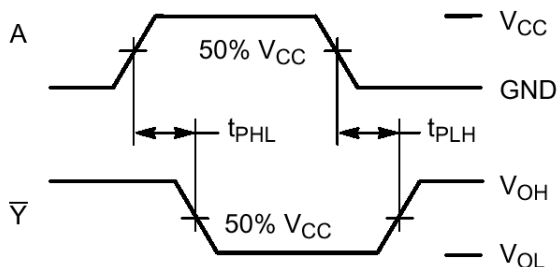
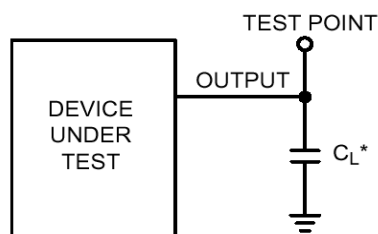


Figure 4. Switching Waveforms



*Includes all probe and jig capacitance

Figure 5. Test Circuit

DEVICE ORDERING INFORMATION

| Device Order Number | Device Nomenclature | | | | | | Package Type (Name/SOT#/Common Name) | Tape and Reel Size |
|---------------------|---------------------|-----------------------|------------|-----------------|----------------|--------------------|---|-------------------------------|
| | Circuit Indicator | Temp Range Identifier | Technology | Device Function | Package Suffix | Tape & Reel Suffix | | |
| MC74VHC1GU04DFT1 | MC | 74 | VHC1G | U04 | DF | T1 | SC-70/SC-88A/ SOT-353 | 178 mm (7 in) 3000 Unit |
| MC74VHC1GU04DFT2 | MC | 74 | VHC1G | U04 | DF | T2 | SC-70/SC-88A/ SOT-353 | 178 mm (7 in) 3000 Unit |
| MC74VHC1GU04DFT4 | MC | 74 | VHC1G | U04 | DF | T4 | SC-70/SC-88A/ SOT-353 | 330 mm (13 in) 10,000 Unit |
| MC74VHC1GU04DTT1 | MC | 74 | VHC1G | U04 | DT | T1 | SOT-23/TSOPS/ SC-59 | 178 mm (7 in) 3000 Unit |
| MC74VHC1GU04DTT3 | MC | 74 | VHC1G | U04 | DT | T3 | SOT-23/TSOPS/ SC-59 | 330 mm (13 in) 10,000 Unit |